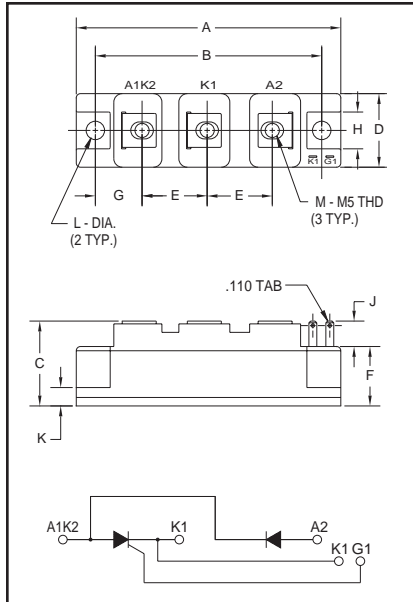


**SCR/Diode
POW-R-BLOK™ Modules
55 Amperes/1200-1600 Volts**



Outline Drawing

Dimension	Inches	Millimeters
A	3.681 Max.	93.5 Max.
B	3.150	80
C	1.181 Max.	30 Max.
D	1.024 Max.	26 Max.
E	0.906	23
F	0.827	21
G	0.650	16.5
H	0.512	13
J	0.354	9
K	0.256	6.5
L	0.256 Dia.	Dia. 6.5
M	M5 Metric	M5



**CM421255, CM421655
SCR/Diode
POW-R-BLOK™ Modules
55 Amperes/1200-1600 Volts**

Description:

Powerex SCR/Diode POW-R-BLOK™ Modules are designed for use in applications requiring Half-Control and isolated packaging. The modules are isolated for easy mounting with other components on common heatsinks.

Features:

- Isolated Mounting
- Glass Passivated Chips
- Metal Baseplate
- Low Thermal Impedance

Applications:

- Battery Supplies
- Bridge Circuits
- AC and DC Motor Control
- Tap Changers
- Lighting Control

Ordering Information:

Select the complete eight digit module part number you desire from the table below. Example: CM421255 is a 1200 Volt, 55 Ampere SCR/Diode POW-R-BLOK™ Module.

Type	Voltage Volts (x100)	Current Rating Amperes (55)
CM42	12 16	55



Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (724) 925-7272

CM421255, CM421655
SCR/Diode POW-R-BLOK™ Modules
55 Amperes/1200-1600 Volts

Absolute Maximum Ratings

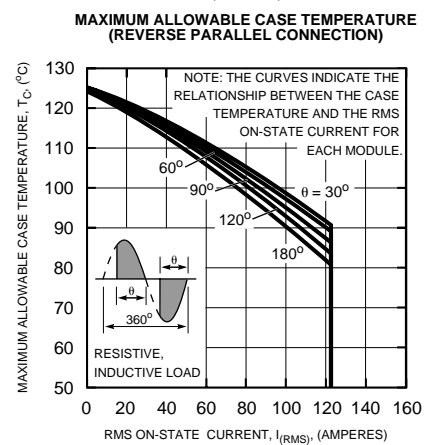
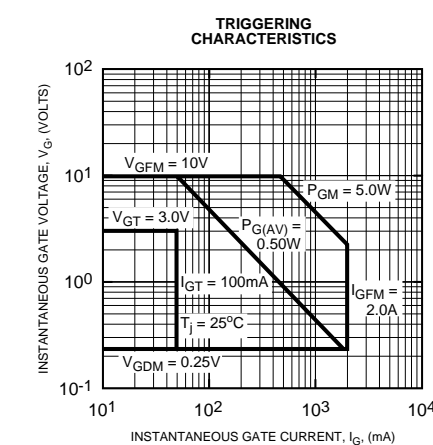
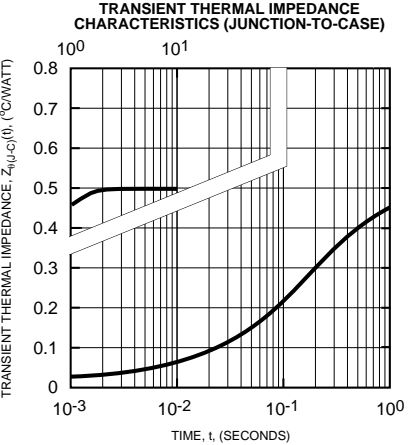
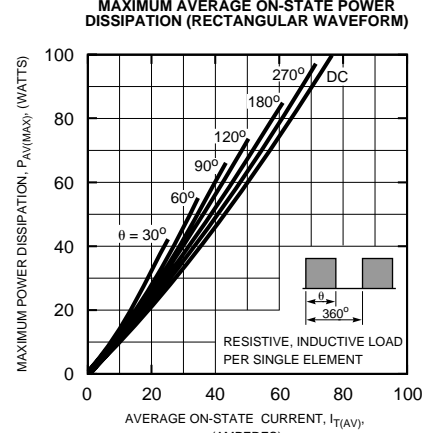
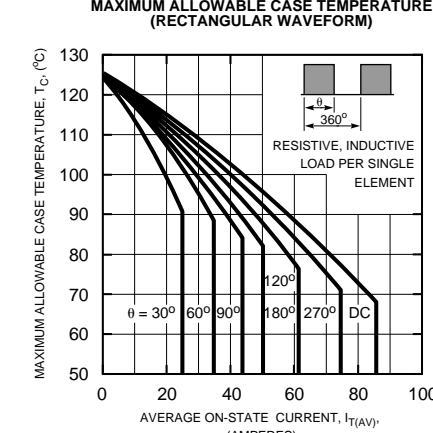
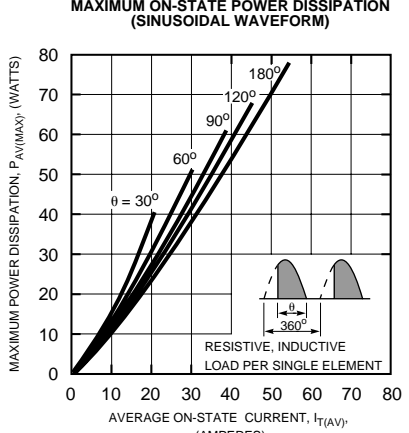
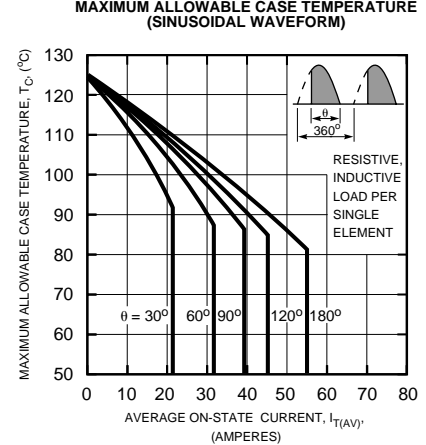
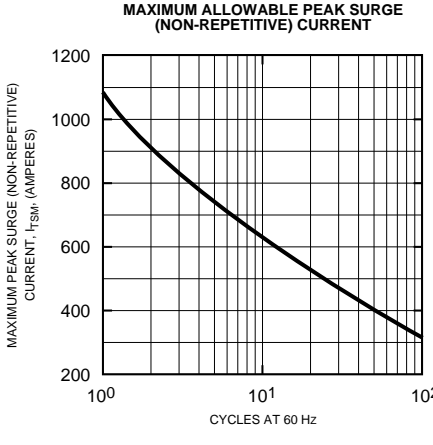
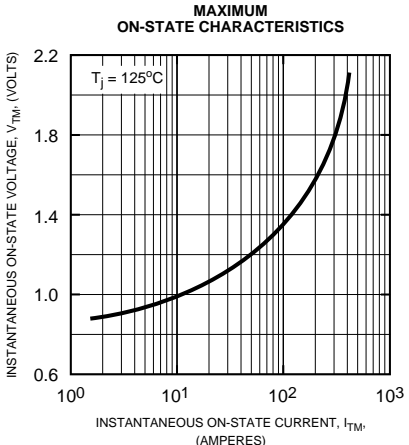
Characteristics	Symbol	CM421255	CM421655	Units
Peak Forward Blocking Voltage	V_{DRM}	1200	1600	Volts
Transient Peak Forward Blocking Voltage (Non-Repetitive), $t < 5\text{ms}$	V_{DSM}	1350	1700	Volts
DC Forward Blocking Voltage	$V_{D(DC)}$	960	1280	Volts
Peak Reverse Blocking Voltage	V_{RRM}	1200	1600	Volts
Transient Peak Reverse Blocking Voltage (Non-Repetitive), $t < 5\text{ms}$	V_{RSM}	1350	1700	Volts
DC Reverse Blocking Voltage	$V_{R(DC)}$	960	1280	Volts
RMS On-State Current	$I_T(\text{RMS}), I_F(\text{RMS})$	86	86	Amperes
Average On-State Current, $T_C = 81^\circ\text{C}$	$I_T(\text{AV}), I_F(\text{AV})$	55	55	Amperes
Peak One-Cycle Surge (Non-Repetitive) On-State Current (60Hz)	I_{TSM}, I_{FSM}	1100	1100	Amperes
Peak One-Cycle Surge (Non-Repetitive) On-State Current (50Hz)	I_{TSM}, I_{FSM}	1000	1000	Amperes
I^2t (for Fusing), 8.3 milliseconds	I^2t	5000	5000	A^2sec
Critical Rate-of-Rise of On-State Current*	di/dt	100	100	Amperes/ μs
Peak Gate Power Dissipation	P_{GM}	5.0	5.0	Watts
Average Gate Power Dissipation	$P_{G(\text{AV})}$	0.5	0.5	Watts
Peak Forward Gate Voltage	V_{GFM}	10	10	Volts
Peak Reverse Gate Voltage	V_{GRM}	5.0	5.0	Volts
Peak Forward Gate Current	I_{GFM}	2.0	2.0	Amperes
Storage Temperature	T_{STG}	-40 to 125	-40 to 125	$^\circ\text{C}$
Operating Temperature	T_j	-40 to 125	-40 to 125	$^\circ\text{C}$
Maximum Mounting Torque M6 Mounting Screw	—	26	26	in.-lb.
Maximum Mounting Torque M5 Terminal Screw	—	17	17	in.-lb.
Module Weight (Typical)	—	160	160	Grams
V Isolation	V_{RMS}	2500	2500	Volts

* $T_j = 125^\circ\text{C}$, $I_G = 0.5\text{A}$, $V_D = 1/2 V_{DRM}$

Electrical and Thermal Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

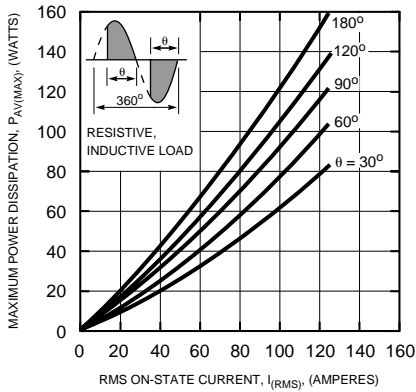
Characteristics	Symbol	Test Conditions	CM421255/CM421655	Units
Blocking State Maximums				
Forward Leakage Current, Peak	I_{DRM}	$T_j = 125^\circ\text{C}$, $V_{DRM} = \text{Rated}$	10	mA
Reverse Leakage Current, Peak	I_{RRM}	$T_j = 125^\circ\text{C}$, $V_{RRM} = \text{Rated}$	10	mA
Conducting State Maximums				
Peak On-State Voltage	V_{FM}, V_{TM}	$I_{FM} = 165\text{A}$, $I_{TM} = 165\text{A}$	1.5	Volts
Switching Minimums				
Critical Rate-of-Rise of Off-State Voltage	dv/dt	$T_j = 125^\circ\text{C}$, $V_D = 2/3 V_{DRM}$	500	Volts/ μs
Thermal Maximums				
Thermal Resistance, Junction-to-Case	$R_{\theta(J-C)}$	Per Module	0.8	$^\circ\text{C}/\text{Watt}$
Thermal Resistance, Case-to-Sink (Lubricated)	$R_{\theta(C-S)}$	Per Module	0.2	$^\circ\text{C}/\text{Watt}$
Gate Parameters Maximums				
Gate Current-to-Trigger	I_{GT}	$V_D = 6\text{V}$, $R_L = 2\Omega$	100	mA
Gate Voltage-to-Trigger	V_{GT}	$V_D = 6\text{V}$, $R_L = 2\Omega$	2.0	Volts
Non-Triggering Gate Voltage	V_{GDM}	$T_j = 125^\circ\text{C}$, $V_D = 1/2 V_{DRM}$	0.25	Volts

CM421255, CM421655
SCR/Diode POW-R-BLOK™ Modules
 55 Amperes/1200-1600 Volts



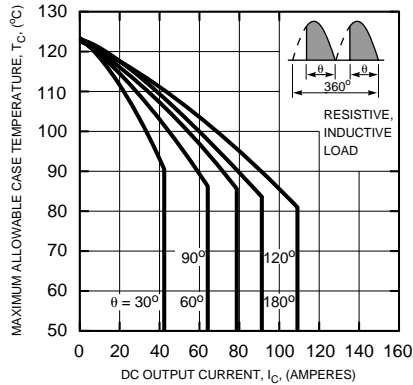
CM421255, CM421655
SCR/Diode POW-R-BLOK™ Modules
 55 Amperes/1200-1600 Volts

**MAXIMUM ON-STATE POWER DISSIPATION
 (REVERSE PARALLEL CONNECTION)**



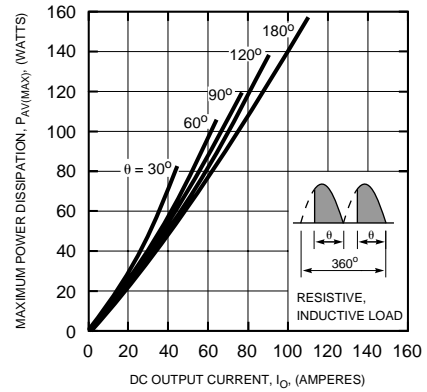
NOTE: THE CURVES INDICATE THE RELATIONSHIP BETWEEN THE AVERAGE ON-STATE POWER DISSIPATION PER MODULE AND THE RMS ON-STATE CURRENT.

**MAXIMUM ALLOWABLE CASE TEMPERATURE
 (SINGLE PHASE BRIDGE CONNECTION)**



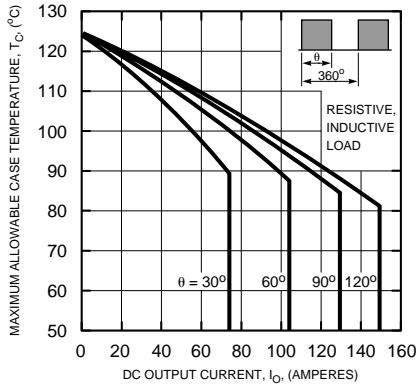
NOTE: THE CURVES INDICATE THE RELATIONSHIP BETWEEN THE CASE TEMPERATURE AND THE DC OUTPUT CURRENT (FOR TWO ELEMENTS) WHEN USED IN THE SINGLE PHASE BRIDGE CONFIGURATION.

**MAXIMUM ON-STATE POWER DISSIPATION
 (SINGLE PHASE BRIDGE CONNECTION)**



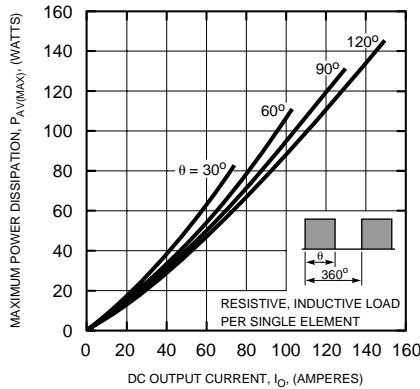
NOTE: THE CURVES INDICATE THE RELATIONSHIP BETWEEN THE AVERAGE ON-STATE POWER DISSIPATION AND THE DC OUTPUT CURRENT FOR THE SINGLE PHASE BRIDGE CONFIGURATION (POWER DISSIPATION EXPRESSED FOR EACH MODULE AND DC OUTPUT CURRENT EXPRESSED FOR THE PAIR)

**MAXIMUM ALLOWABLE CASE TEMPERATURE
 (THREE PHASE BRIDGE CONNECTION)**



NOTE: THE CURVES INDICATE THE RELATIONSHIP BETWEEN THE CASE TEMPERATURE AND THE DC OUTPUT CURRENT (FOR THREE MODULES) IN THE THREE PHASE CONFIGURATION.

**MAXIMUM ON-STATE POWER DISSIPATION
 (THREE PHASE BRIDGE CONNECTION)**



NOTE: THE CURVES INDICATE THE RELATIONSHIP BETWEEN THE ON-STATE POWER DISSIPATION (PER MODULE) AND THE DC OUTPUT CURRENT (FOR THREE MODULES) IN THE THREE PHASE BRIDGE CONFIGURATION.